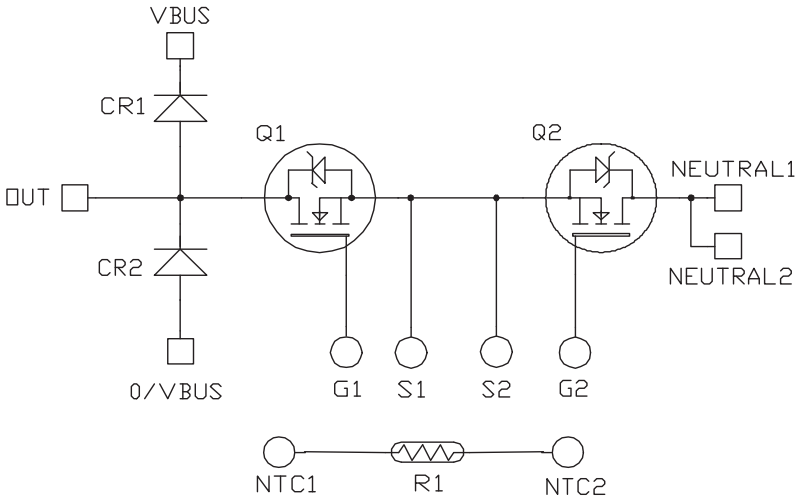
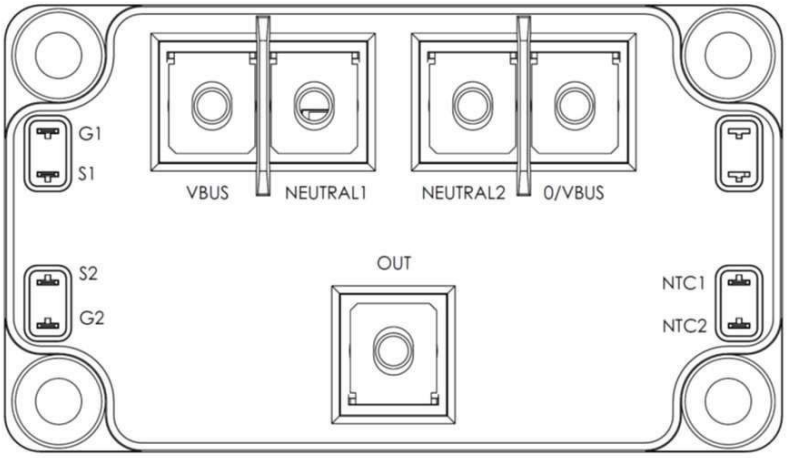
MSCSM120VR1M062CT6AG

Vienna Rectifier SiC MOSFET Power Module

Product Overview

The MSCSM120VR1M062CT6AG device is a Vienna rectifier 1200V, 420A silicon carbide (SiC) power module.





Note: All ratings at T_J = 25 °C, unless otherwise specified.

⚠ CAUTION These devices are sensitive to electrostatic discharge. Proper handling procedures must be followed.

Features

The following are the key features of MSCSM120VR1M062CT6AG device:

- SiC Power MOSFET
  - Low $R_{DS(on)}$
  - High temperature performance
- SiC Schottky Diode
  - Zero reverse recovery
  - Zero forward recovery
  - Temperature independent switching behavior
  - Positive temperature coefficient on V_F
- Kelvin source for easy drive
- Low stray inductance
- M5 power connectors
- Internal thermistor for temperature monitoring
- Aluminum Nitride (AlN) substrate for improved thermal performance

Benefits

The following are the benefits of MSCSM120VR1M062CT6AG device:

- Outstanding performance at high frequency operation
- High-power and high-efficiency rectifiers and converters
- Direct mounting to heatsink (isolated package)
- Low junction-to-case thermal resistance
- Low profile
- RoHS compliant

Applications

The following are the applications of MSCSM120VR1M062CT6AG device:

- Power factor correction
- Switched mode power supplies
- Uninterruptible power supplies

1. Electrical Specifications

The following sections show the electrical specifications of the MSCSM120VR1M062CT6AG device.

1.1 SiC MOSFET Characteristics (Per SiC MOSFET)

The following table lists the absolute maximum ratings (per SiC MOSFET) of the MSCSM120VR1M062CT6AG device.

Table 1-1. Absolute Maximum Ratings

Symbol	Parameter		Maximum Ratings	Unit
V_{DSS}	Drain-Source voltage		1200	V
I_D	Continuous drain current	T_C = 25 °C	420	A
		T_C = 80 °C	334	
I_{DM}	Pulsed drain current		840	
V_{GS}	Gate-Source voltage		–10/23	V
$R_{DS(on)}$	Drain-Source ON resistance		6.2	mΩ
P_D	Power dissipation	T_C = 25 °C	1753	W

The following table lists the electrical characteristics (per SiC MOSFET) of the MSCSM120VR1M062CT6AG device.

Table 1-2. Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min.	Typ.	Max.	Unit
I_{DSS}	Zero gate voltage drain current	V_{GS} = 0V; V_{DS} = 1200V		—	50	500	µA
$R_{DS(on)}$	Drain-Source on resistance	V_{GS} = 20V I_D = 200A	T_J = 25 °C	—	5	6.2	mΩ
			T_J = 175 °C	—	8	—	
$V_{GS(th)}$	Gate threshold voltage	V_{GS} = V_{DS}; I_D = 15 mA		1.8	2.8	—	V
I_{GSS}	Gate-Source leakage current	V_{GS} = 20V; V_{DS} = 0V		—	—	500	nA

The following table lists the dynamic characteristics (per SiC MOSFET) of the MSCSM120VR1M062CT6AG device.

Table 1-3. Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min.	Typ.	Max.	Unit
C_{iss}	Input capacitance	V_{GS} = 0V		—	15.1	—	nF
C_{oss}	Output capacitance	V_{DS} = 1000V		—	1.4	—	
C_{rss}	Reverse transfer capacitance	f = 1 MHz		—	0.13	—	
Q_g	Total gate charge	V_{GS} = –5V/20V		—	1160	—	nC
Q_{gs}	Gate-source charge	V_{Bus} = 800V		—	205	—	
Q_{gd}	Gate-drain charge	I_D = 200A		—	250	—	
$T_{d(on)}$	Turn-on delay time	V_{GS} = –5V/20V		—	56	—	ns
T_r	Rise time	V_{Bus} = 600V		—	55	—	
$T_{d(off)}$	Turn-off delay time	I_D = 250A		—	166	—	
T_f	Fall time	T_J = 150 °C R_{GON} = 1.6Ω R_{GOFF} = 0.9Ω			67	—	
E_{on}	Turn-on energy	V_{GS} = –5V/20V	T_J = 150 °C	—	5	—	mJ
E_{off}	Turn-off energy	V_{Bus} = 600V I_D = 250A R_{GON} = 1.6Ω R_{GOFF} = 0.9Ω	T_J = 150 °C	—	4.5	—	
R_{Gint}	Internal gate resistance			—	1.18	—	Ω
R_{thJC}	Junction-to-case thermal resistance			—	—	0.086	°C/W

The following table lists the body diode ratings and characteristics (per SiC MOSFET) of the MSCSM120VR1M062CT6AG device.

Table 1-4. Body Diode Ratings and Characteristics

Symbol	Characteristic	Test Conditions	Min.	Typ.	Max.	Unit
V_{SD}	Diode forward voltage	V_{GS} = 0V; I_{SD} = 200A	—	4	—	V
		V_{GS} = –5V; I_{SD} = 200A	—	4.2	—	
t_{rr}	Reverse recovery time	I_{SD} = 200A	—	90	—	ns
Q_{rr}	Reverse recovery charge	V_{GS} = –5V	—	2750	—	nC
I_{rr}	Reverse recovery current	V_R = 800V di_F/dt = 5000 A/µs	—	68	—	A

1.2 SiC Diode Ratings and Characteristics (Per SiC Diode)

The following table lists the SiC diode ratings and characteristics of the MSCSM120VR1M062CT6AG device.

Table 1-5. SiC Diode Ratings and Characteristics

Symbol	Characteristic	Test Conditions		Min.	Typ.	Max.	Unit
V_{RRM}	Peak repetitive reverse voltage			—	—	1700	V
I_{RM}	Reverse leakage current	V_R = 1700V	T_J = 25 °C	—	60	1200	µA
			T_J = 175 °C	—	900	—	
I_F	Forward current		T_C = 125 °C	—	180	—	A
V_F	Diode forward voltage	I_F = 180A	T_J = 25 °C	—	1.5	1.8	V
			T_J = 175 °C	—	2.3	—	
Q_C	Total capacitive charge	V_R = 900V		—	1380	—	nC
C	Total capacitance	f = 1 MHz, V_R = 600V		—	1002	—	pF
		f = 1 MHz, V_R = 900V		—	828	—	
R_{thJC}	Junction-to-case thermal resistance			—	—	0.1	°C/W

1.3 Thermal and Package Characteristics

The following table lists the thermal and package characteristics of the MSCSM120VR1M062CT6AG device.

Table 1-6. Thermal and Package Characteristics

Symbol	Characteristic			Min.	Max.	Unit
V_{ISOL}	RMS isolation voltage, any terminal to case t = 1 min, 50 Hz/60 Hz			4000	—	V
T_J	Operating junction temperature range			–40	175	°C
T_{JOP}	Recommended junction temperature under switching conditions			–40	T_{Jmax}–25	
T_{STG}	Storage case temperature			–40	125	
T_C	Operating case temperature			–40	125	
Torque	Mounting torque	To heatsink	M6	3	5	N.m
		For terminals	M5	2	3.5	
Wt	Package weight			—	300	g

The following table lists the temperature sensor NTC of the MSCSM120VR1M062CT6AG device.

Table 1-7. Temperature Sensor NTC

Symbol	Characteristic		Min.	Typ.	Max.	Unit
R_{25}	Resistance at 25 °C		—	50	—	kΩ
$\Delta R_{25}/R_{25}$	—		—	5	—	%
$B_{25/85}$	T_{25} = 298.15K		—	3952	—	K
ΔB/B	—	T_C = 100 °C	—	4	—	%

$$R_T = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$$

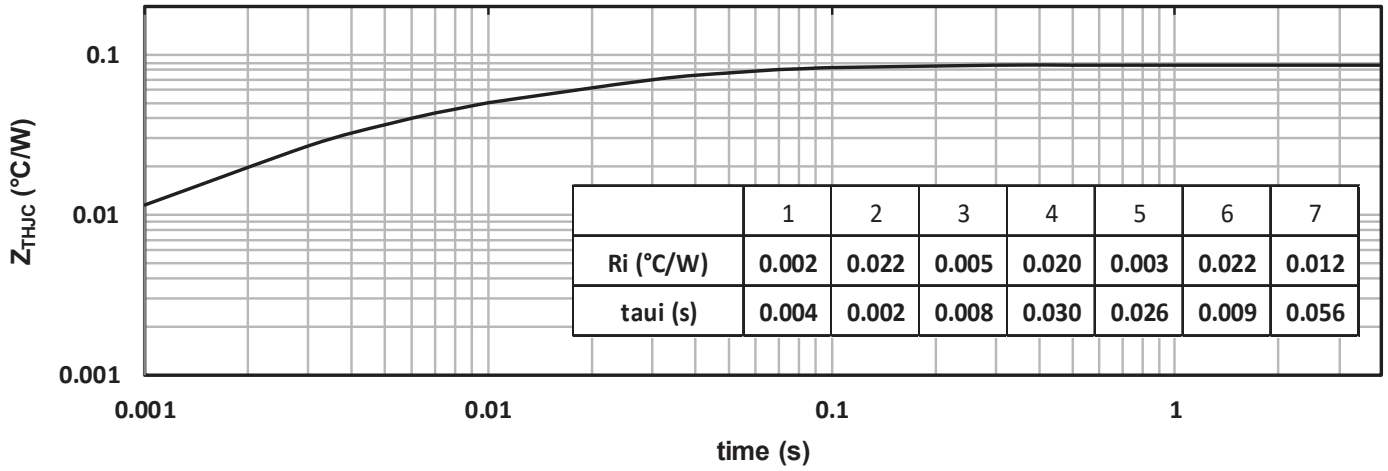
T: Thermistor temperature
R_T: Thermistor value at T

Note: See APT0406—Using NTC Temperature Sensor Integrated into Power Module for more information.

1.4 Typical SiC MOSFET Performance Curve

The following figures show the SiC MOSFET performance curves of the MSCSM120VR1M062CT6AG device.

Figure 1-1. Maximum Thermal Impedance



	1	2	3	4	5	6	7
Ri (°C/W)	0.002	0.022	0.005	0.020	0.003	0.022	0.012
taui (s)	0.004	0.002	0.008	0.030	0.026	0.009	0.056

Figure 1-2. Output Characteristics, T_J = 25 °C

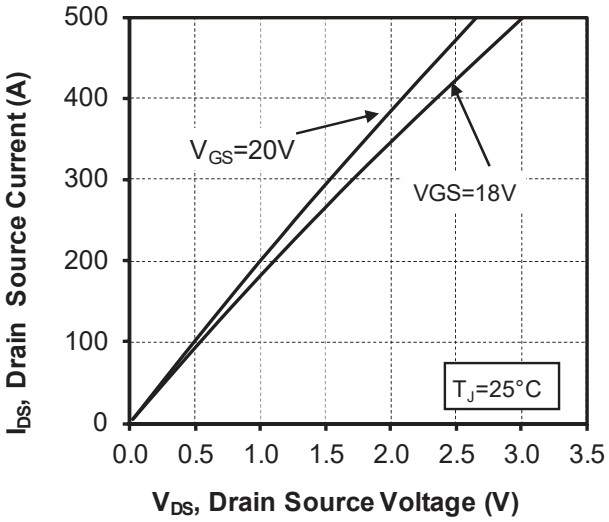


Figure 1-3. Output Characteristics, T_J = 175 °C

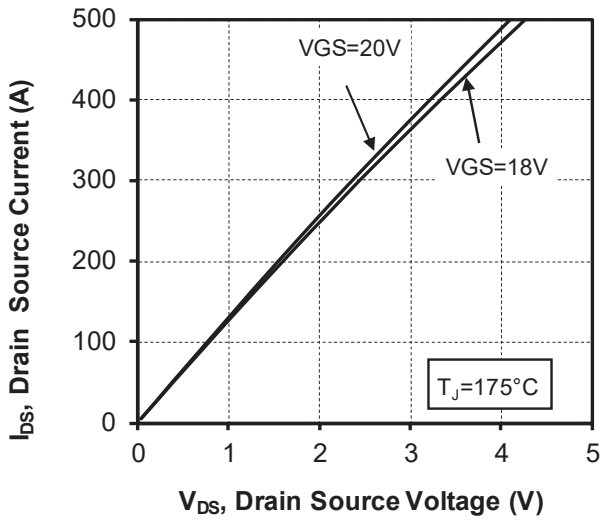


Figure 1-4. Normalized $R_{DS(on)}$ vs. Temperature

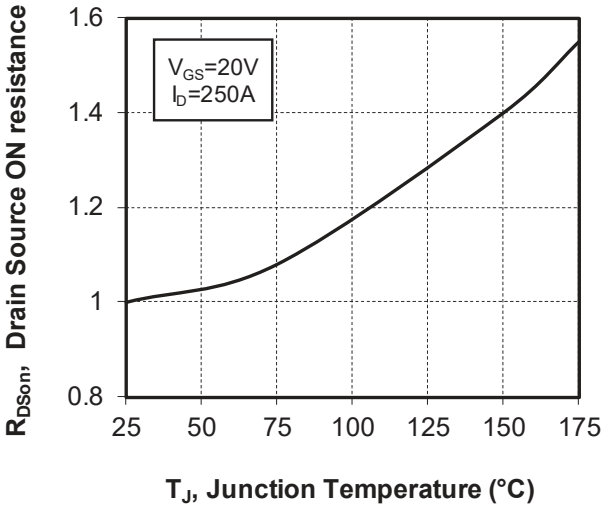


Figure 1-5. Transfer Characteristics

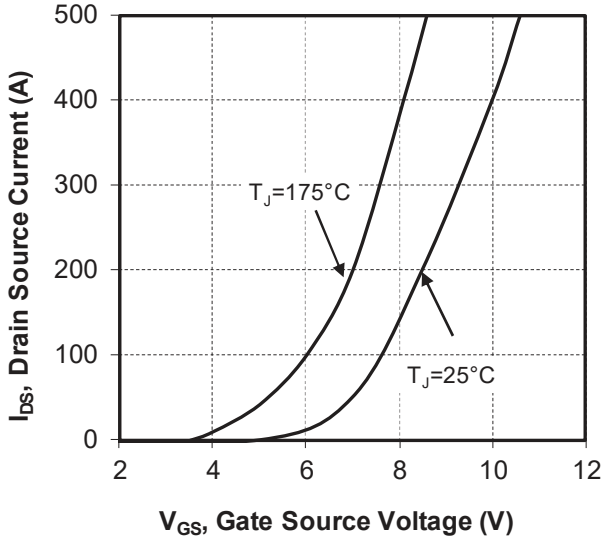


Figure 1-6. Switching Energy vs. Rg

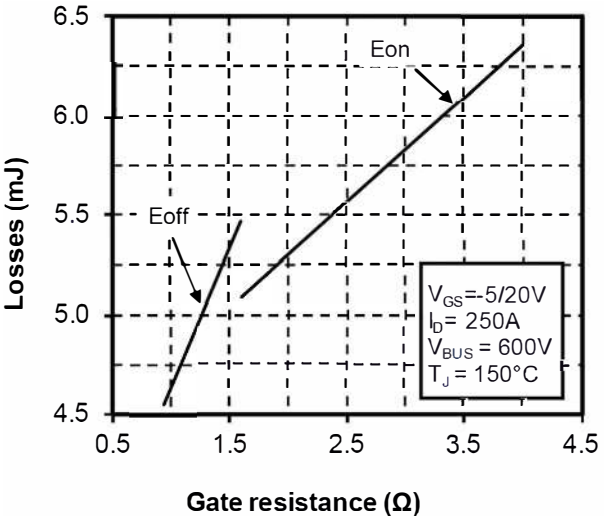


Figure 1-7. Switching Energy vs. Current

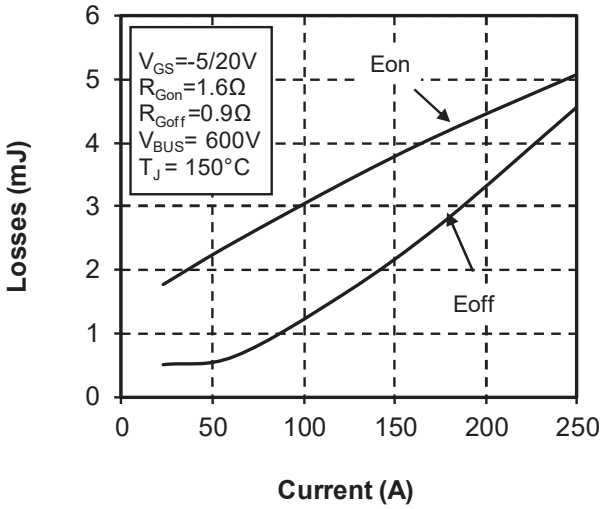


Figure 1-8. Capacitance vs. Drain Source Voltage

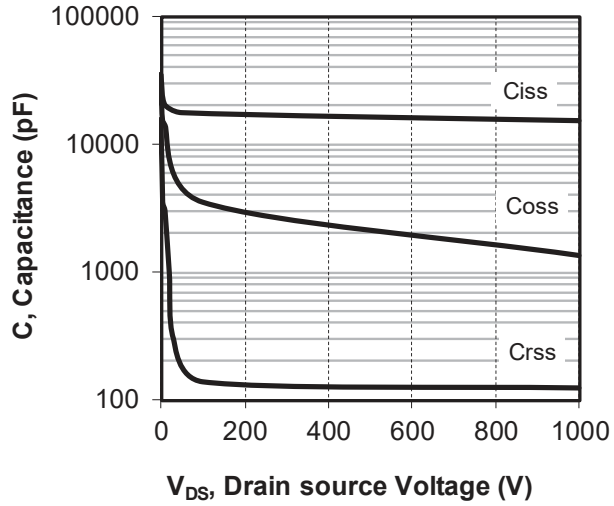


Figure 1-9. Gate Charge vs. Gate Source Voltage

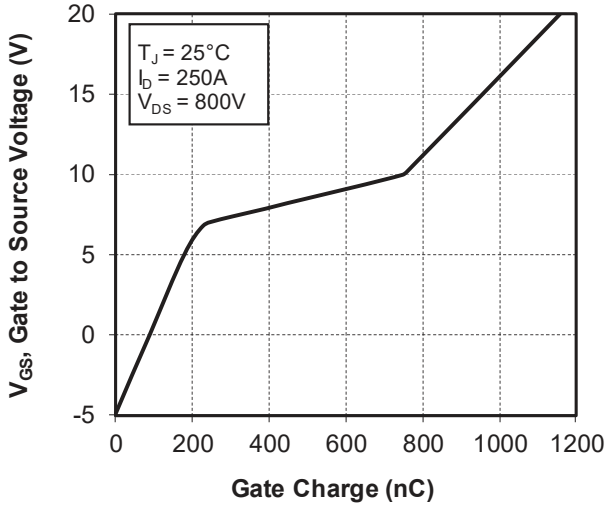


Figure 1-10. Body Diode Characteristics, T_J = 25 °C

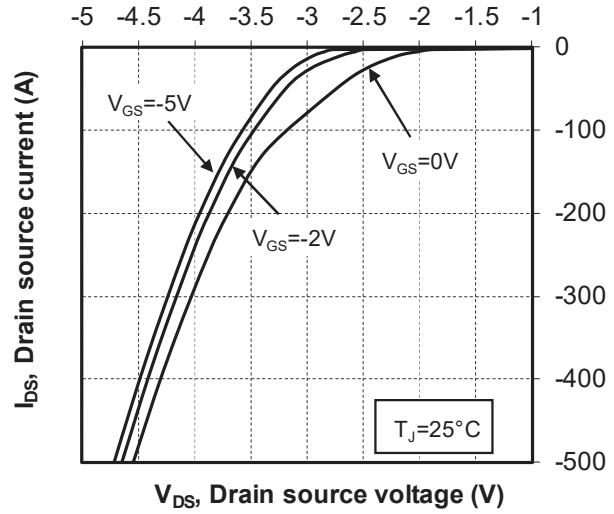


Figure 1-11. 3rd Quadrant Characteristics, T_J = 25 °C

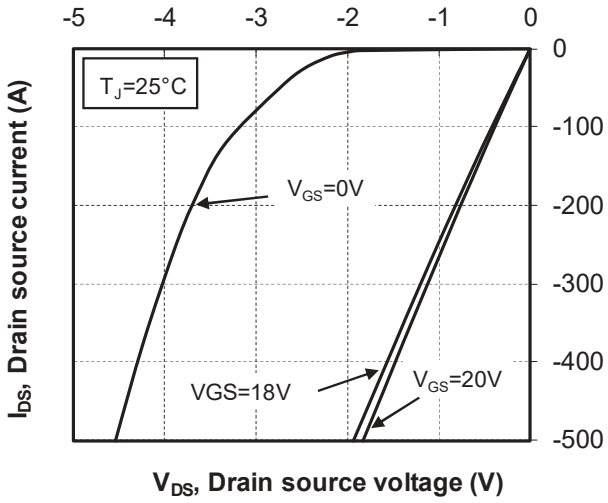


Figure 1-12. Body Diode Characteristics, T_J = 175 °C

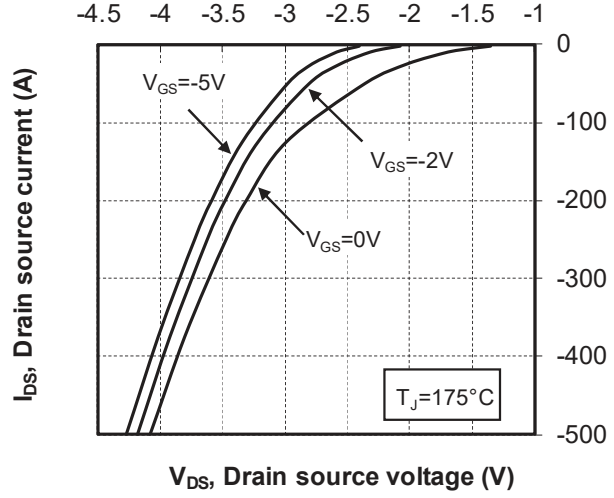


Figure 1-13. 3rd Quadrant Characteristics, T_J = 175 °C

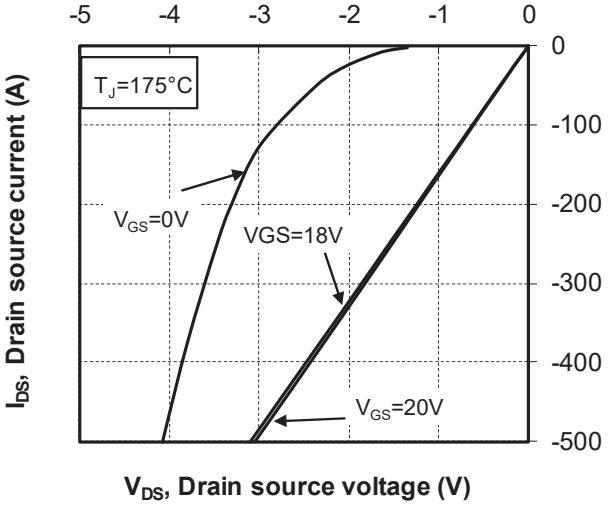
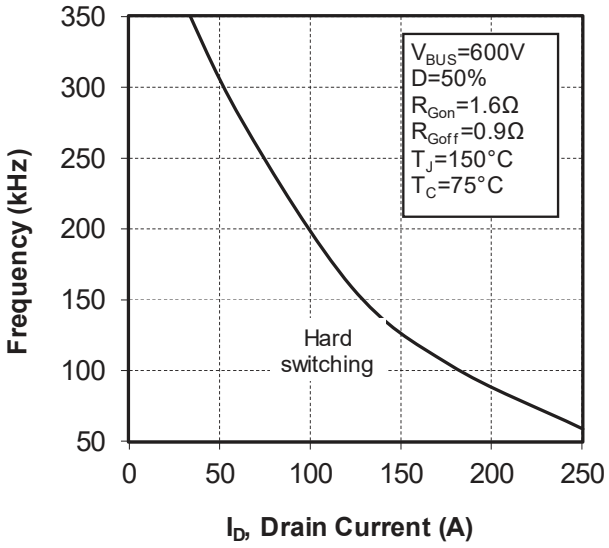


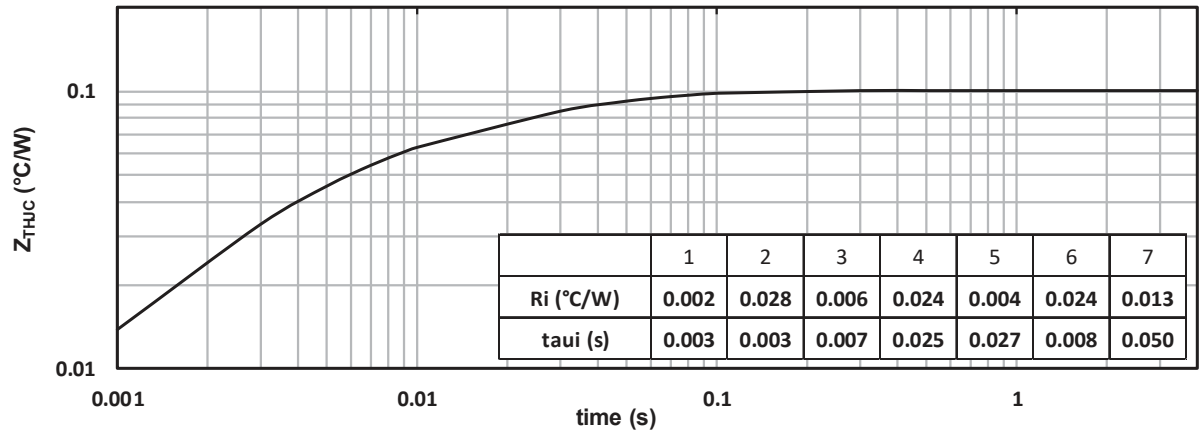
Figure 1-14. Operating Frequency vs. Drain Current



1.5 Typical SiC Diode Performance Curve

The following figures show the SiC diode performance curves of the MSCSM120VR1M062CT6AG device.

Figure 1-15. Maximum Thermal Impedance



	1	2	3	4	5	6	7
Ri (°C/W)	0.002	0.028	0.006	0.024	0.004	0.024	0.013
taui (s)	0.003	0.003	0.007	0.025	0.027	0.008	0.050

Figure 1-16. Forward Characteristics

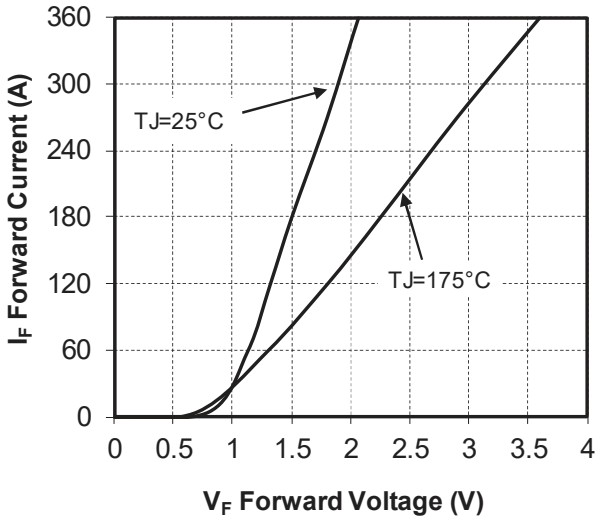
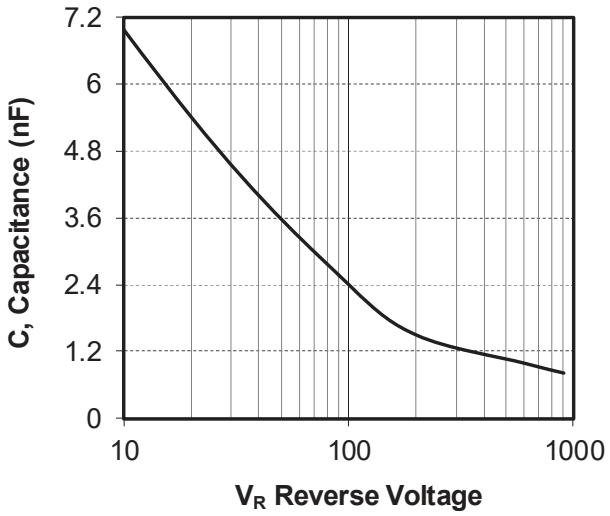


Figure 1-17. Capacitance vs. Reverse Voltage



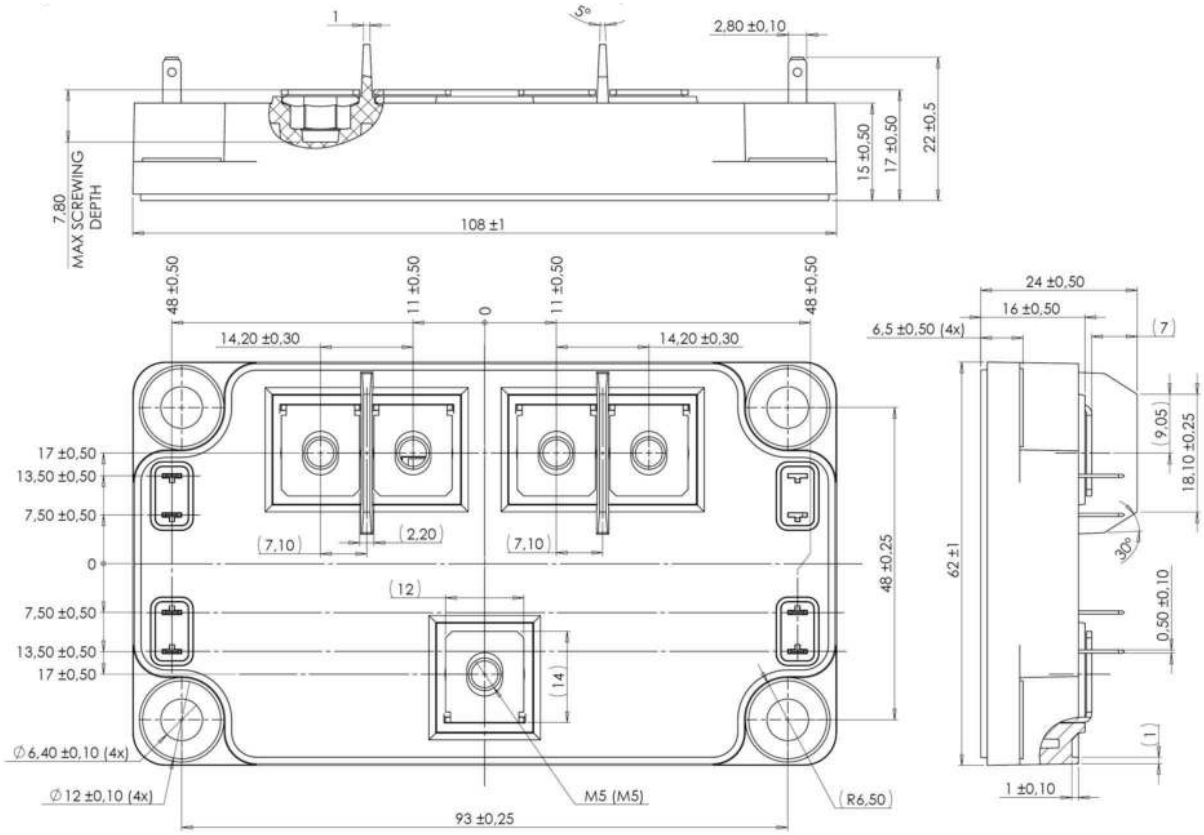
2. Package Specifications

The following section shows the package specification of the MSCSM120VR1M062CT6AG device.

2.1 Package Outline

The following figure shows the package outline drawing of the MSCSM120VR1M062CT6AG device. The dimensions in the following figure are in millimeters.

Figure 2-1. Package Outline Drawing



3. Revision History

Revision	Date	Description
A	08/2022	Initial Revision

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